

# Characterization of laser-assisted and laser-driven EUV sources for metrology applications

**USHIO**

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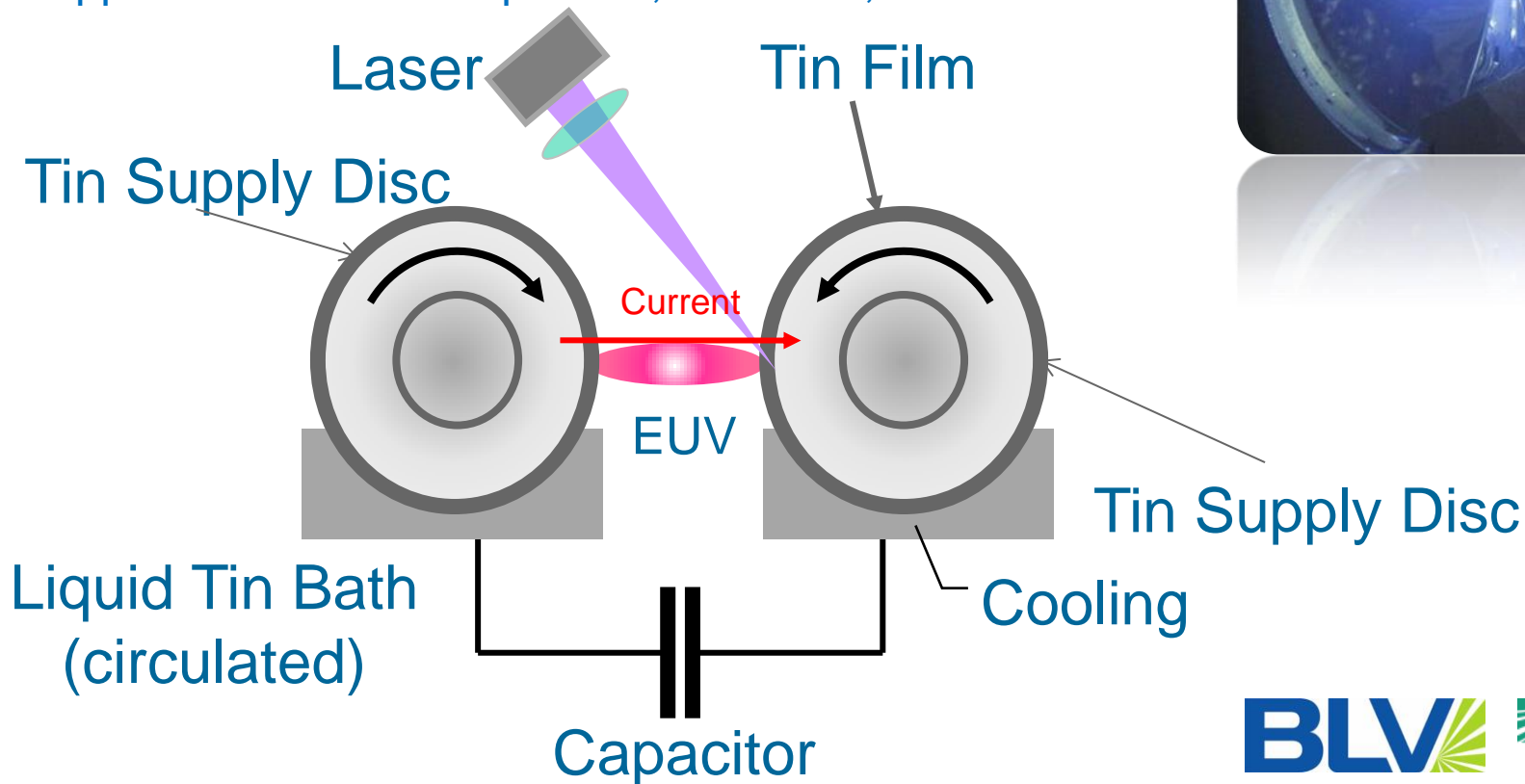
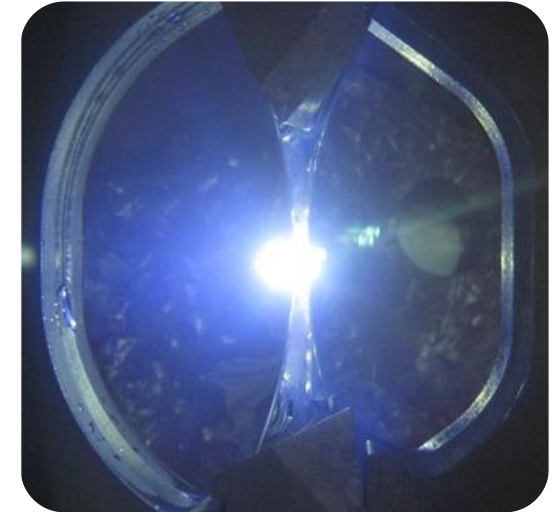


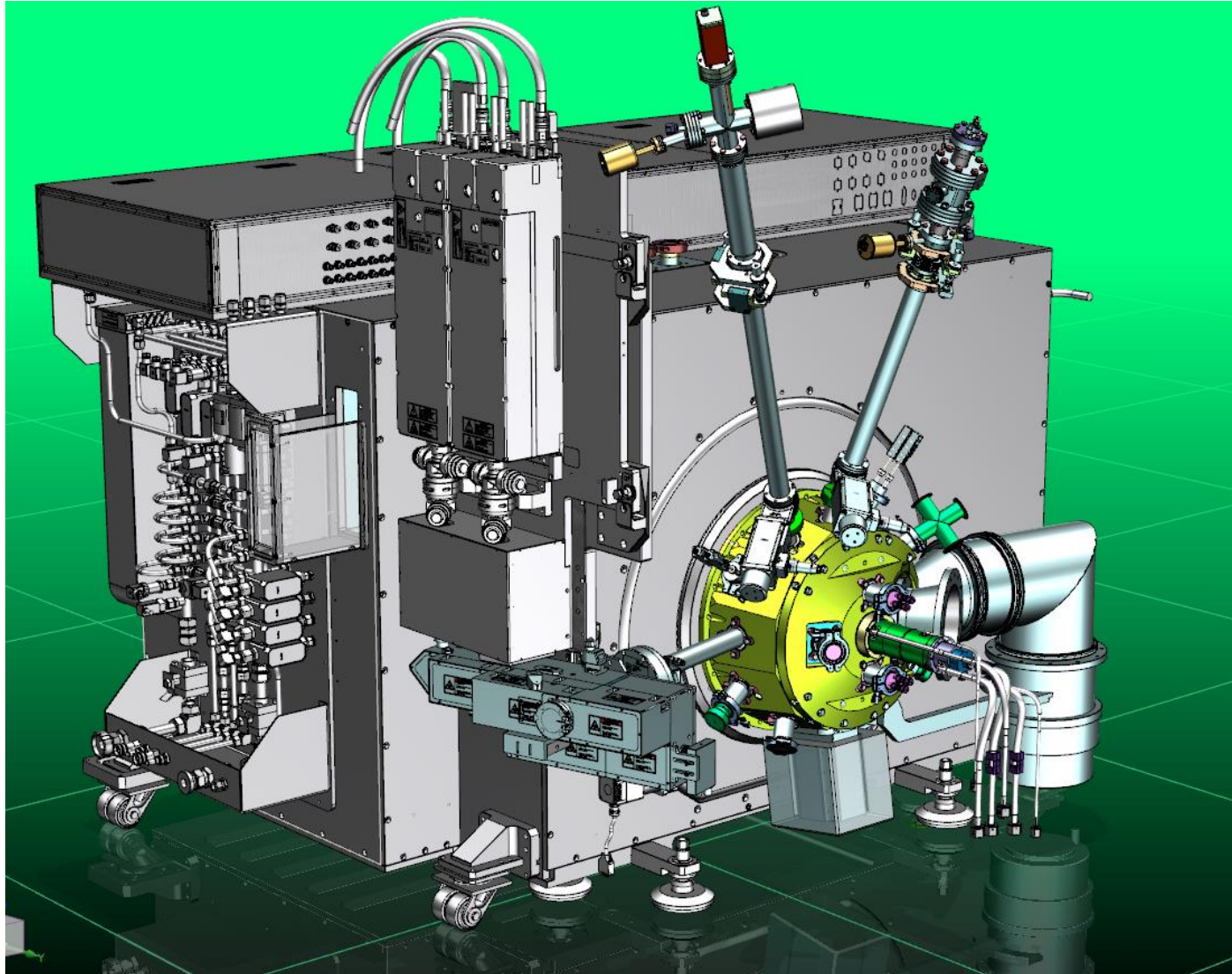
## OUTLINE

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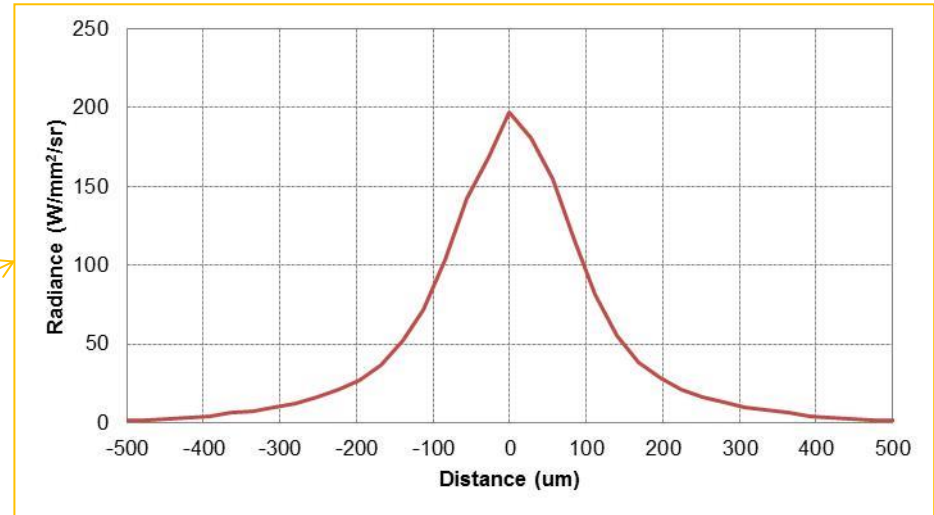
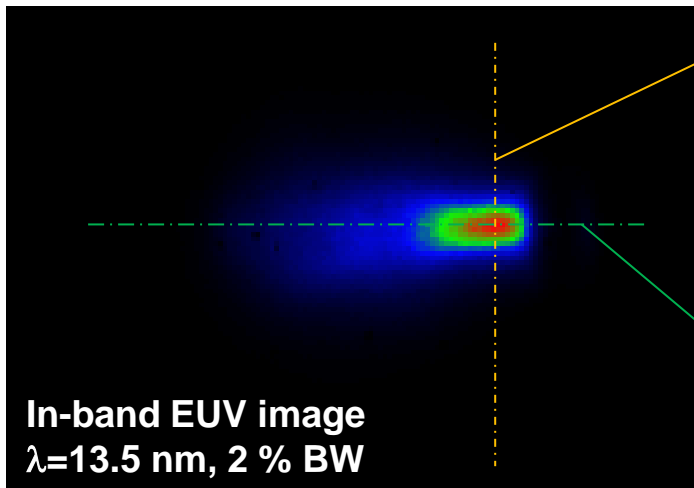
- **LDP source basic principle and performance**
- **LDP source brightness and stability**
- **Compact source basic principle**
- **Compact source brightness and stability**
- **Summary**
-

- Wavelength: 13.5 nm
- High brightness
- Appropriate plasma size (broad profile)
- Stable: no spatial and timing synchronization needed
- Reliable: 24/7 operation
- Clean: powerful debris shield
- Applications: mask inspection, beamline, etc





- ❑ High peak brightness
- ❑ Plasma size smaller than DPP, larger than LPP: good spatial stability



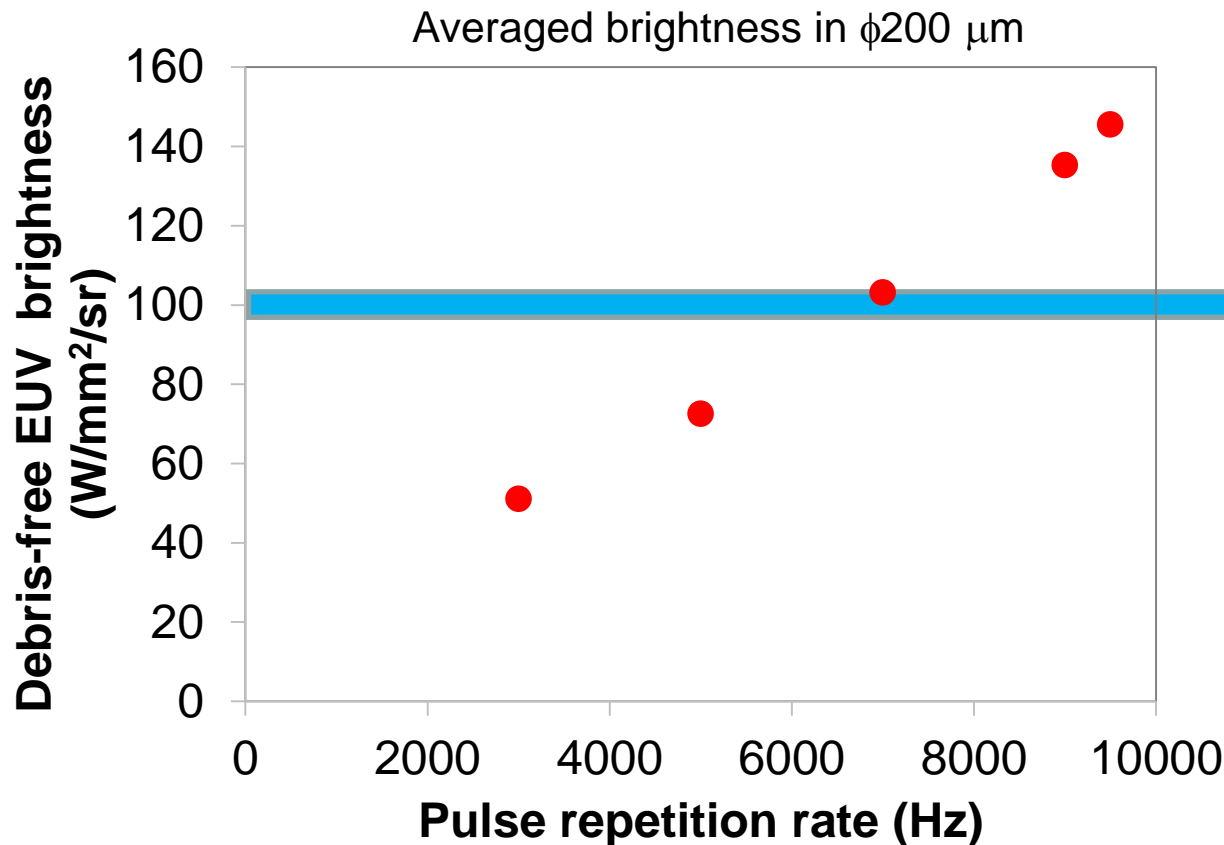
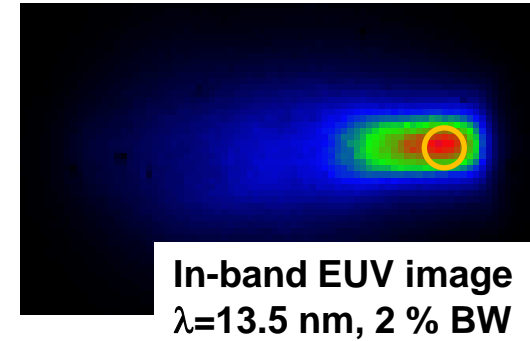
10 kHz, continuous operation

- ❑ Diameter: 200  $\mu\text{m}$  (FWHM)
- ❑ Length: 450  $\mu\text{m}$  (FWHM)

# Brightness behind debris shield: 145 W/mm<sup>2</sup>/sr **USHIO**

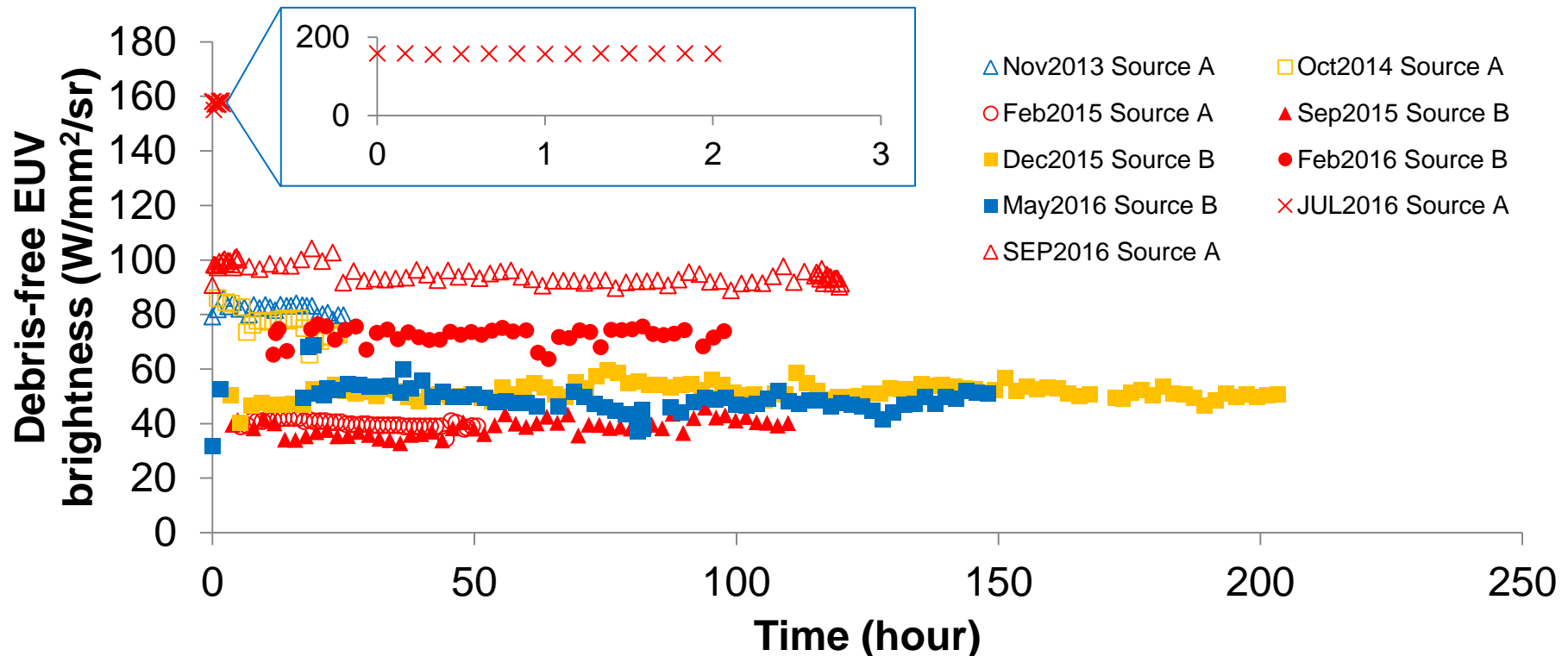
Measured **after debris shield as debris-free EUV photon**

□ Area-averaged brightness: **145 W/mm<sup>2</sup>/sr**



This is what the industry wants.

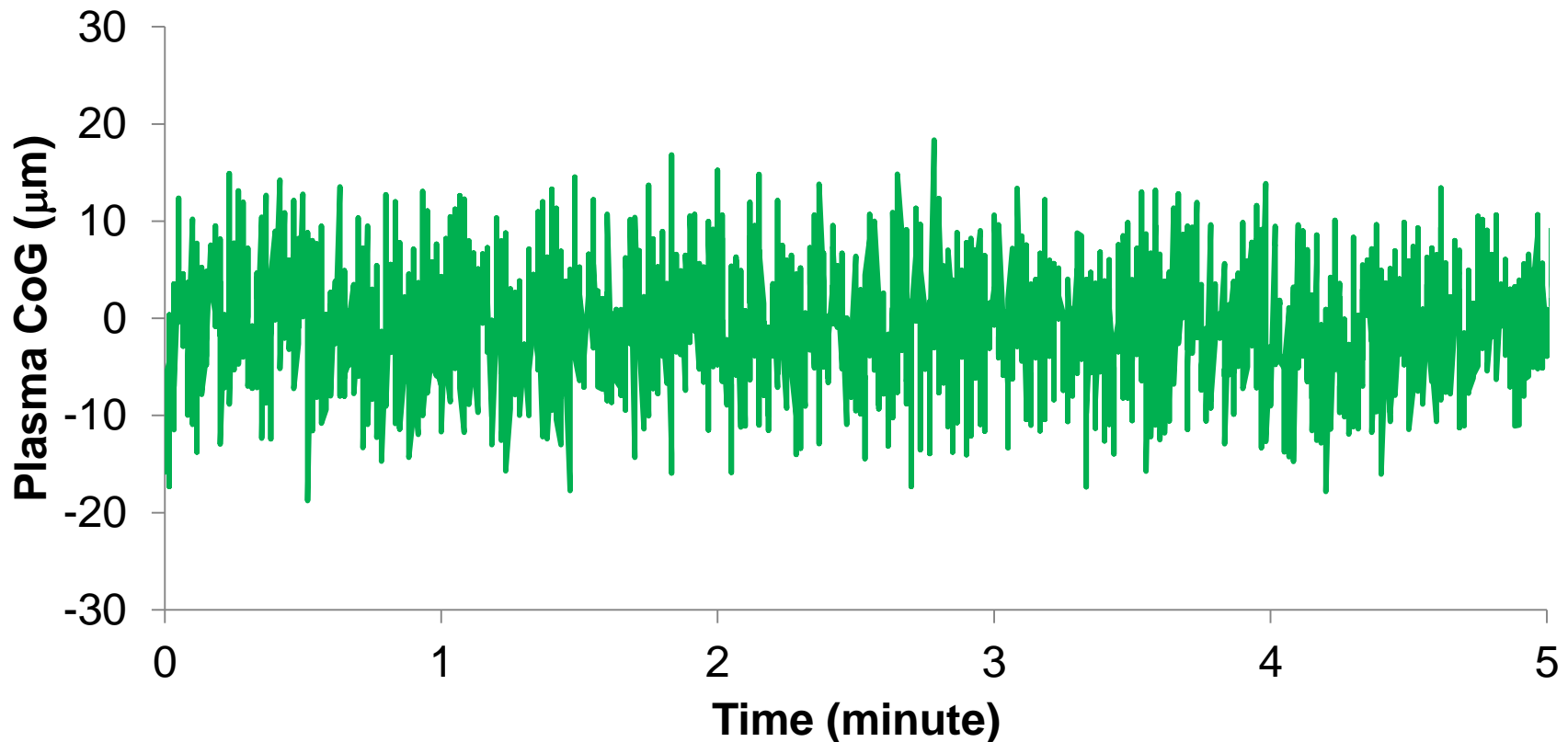
- ❑ Non-interrupted operations of up to 10 days were demonstrated, including
  - ✓ 100 W/mm<sup>2</sup>/sr for 5 days
  - ✓ 160 W/mm<sup>2</sup>/sr for 2 hours
- ❑ Tests continue to improve the system reliability and performance stability.



# Position stability: $\sim 6\ \mu\text{m}$

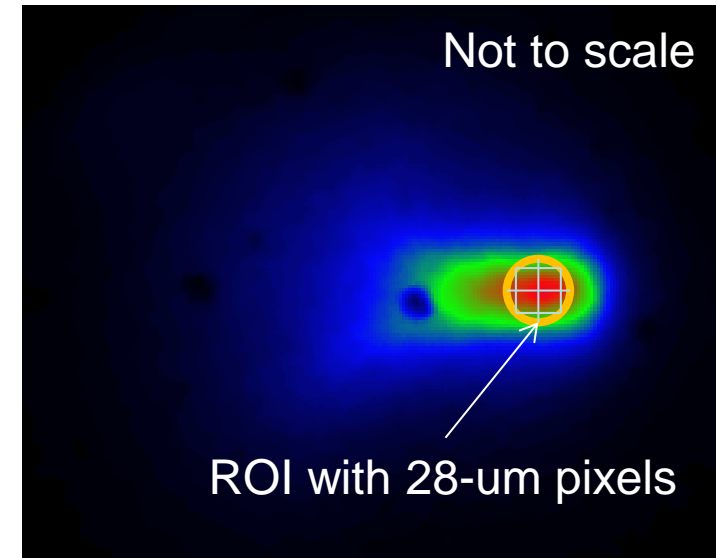
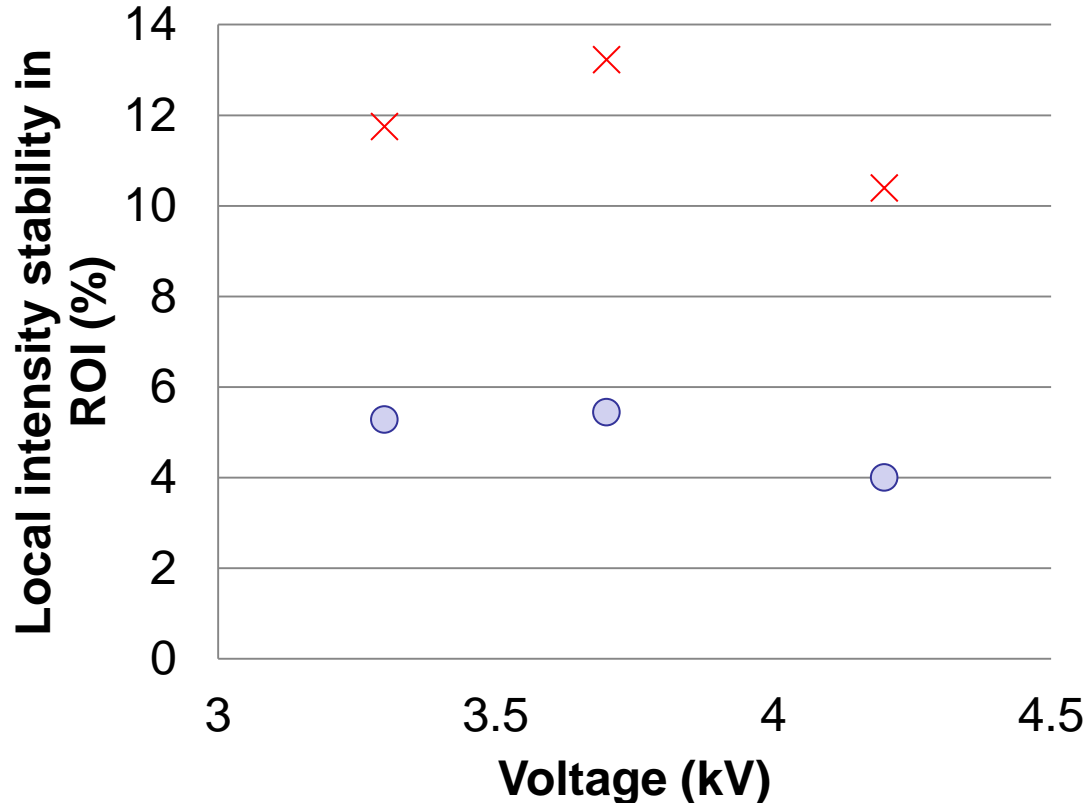
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- ❑ Measured with camera placed on optical axis
  - ❑ Exposure time: 5 ms
- ❑ Standard deviation:  $6.0\sim 6.4\ \mu\text{m}$ 
  - ❑  $<3\%$  of plasma size ( $200\ \mu\text{m}$ )





- ❑ In general, the higher voltage provides better local intensity stability.
- ❑ Faster discharge might be reducing the influence of MHD instability.

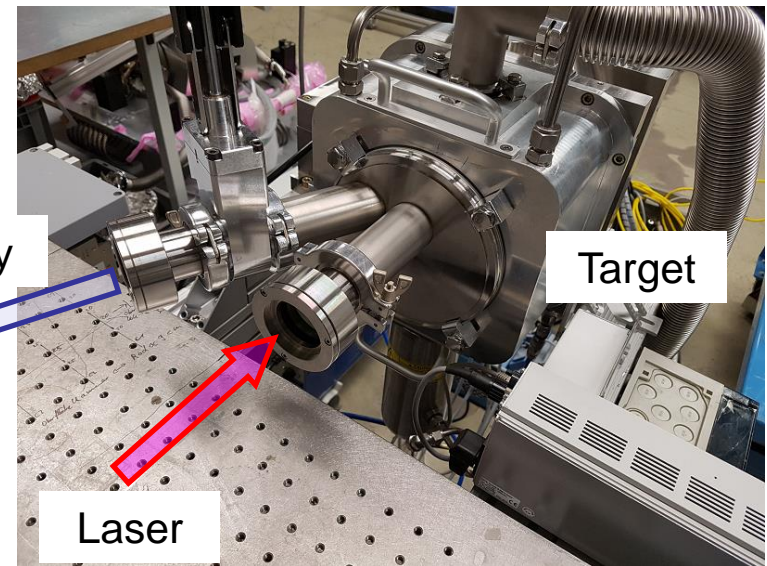
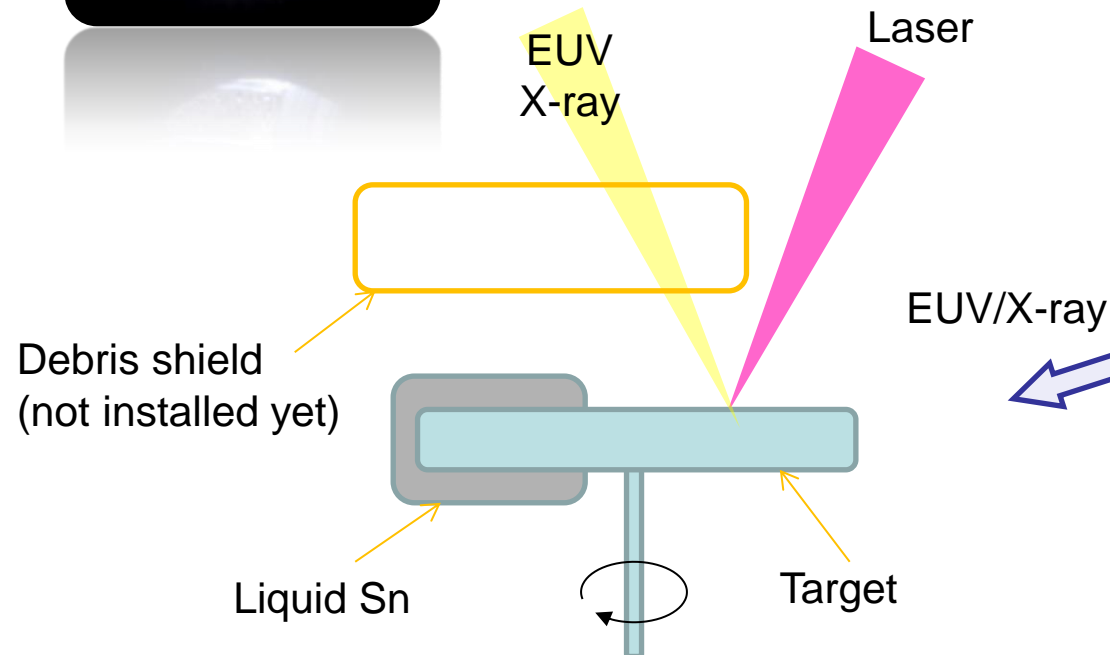


- Best in ROI
- × Worst in ROI

## *Proof-of-concept experimental setup*

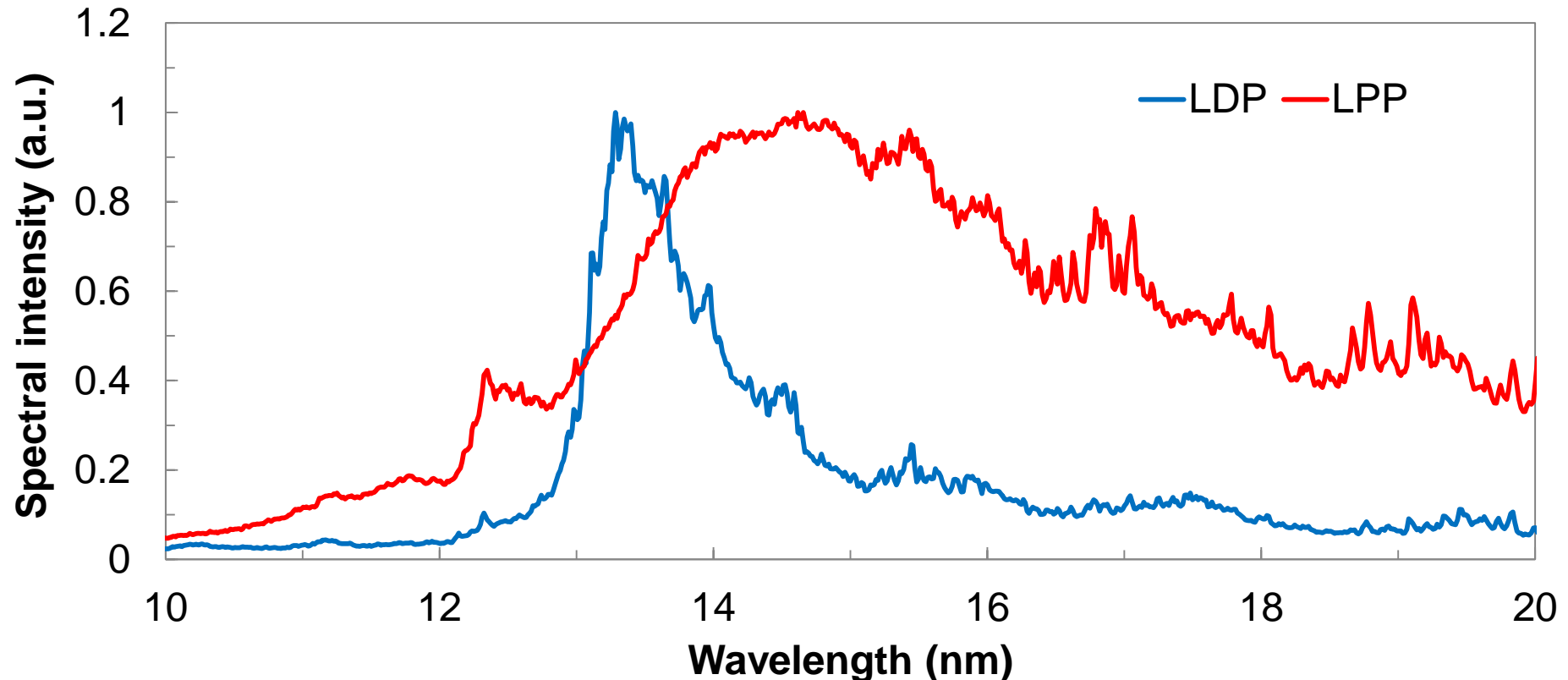


- Laser-driven source
- Low output power
- High output brightness
- Table-top size
- Continuous target supply



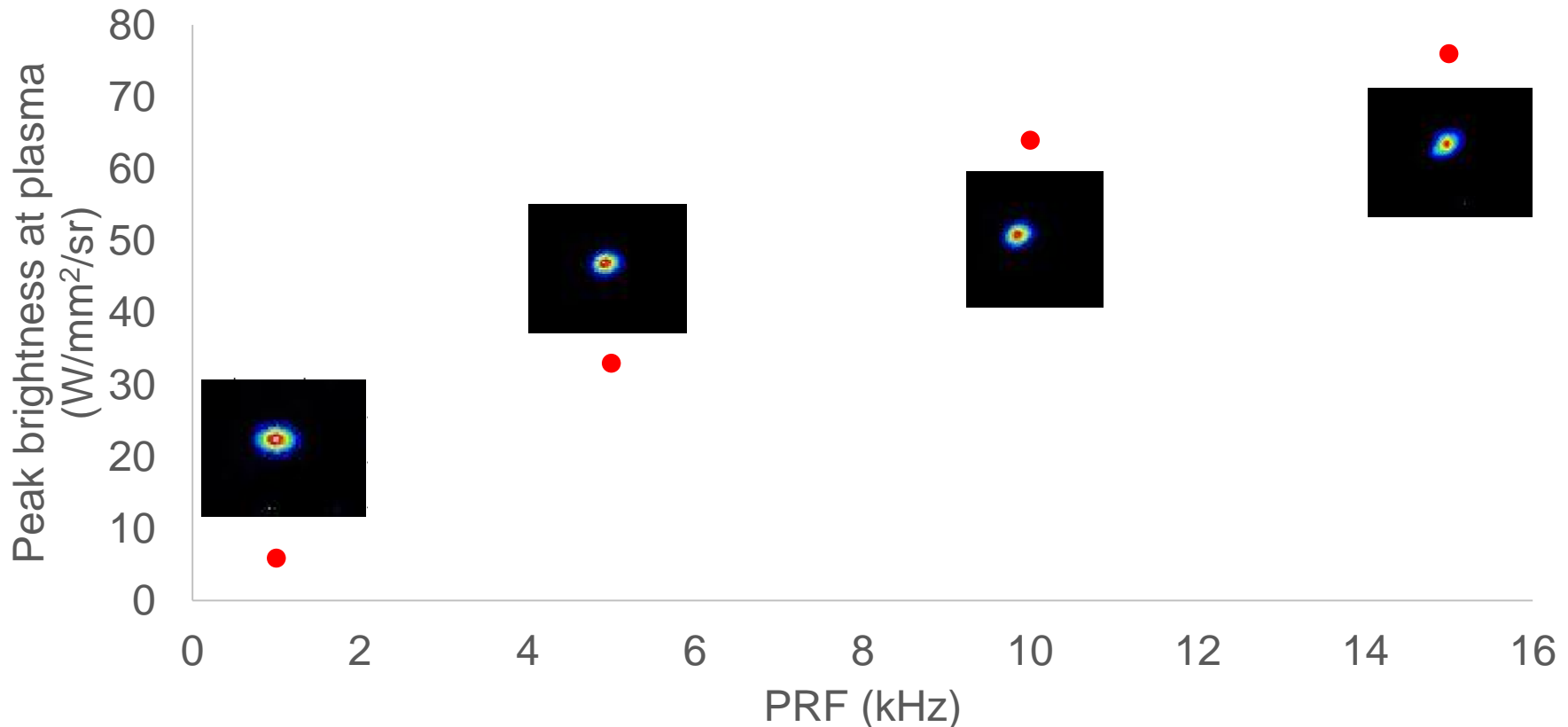
## PoC exp 1

- LPP spectrum is much wider than that of LDP. LDP spectrum is narrower than that of LPP because of its low (suitable) ion density.
- Spectrum optimization by laser parameter adjustment might be possible.



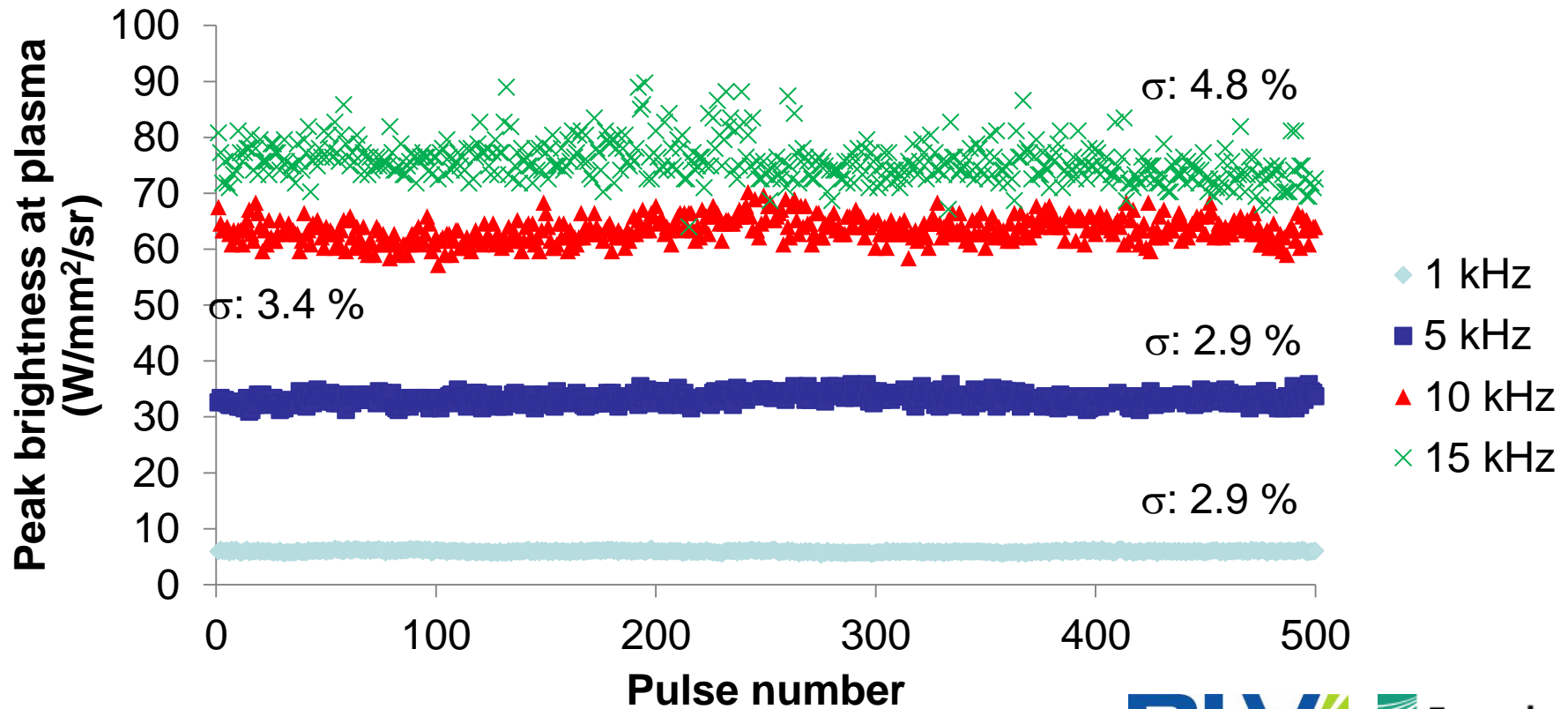
## PoC exp 2

- Scalability up to 15 kHz was tested and 76 W/mm<sup>2</sup>/sr was observed so far.
- CE improvement is planned by increasing laser intensity.
- Mid- and long-term stability will be evaluated at each frequency.



## PoC exp 2

- Short-term stability was confirmed to be good.
- Next step:
  - Study on mid- and long-term stability.



## PoC exp 3

### Laser

Wavelength: 1,064 nm

Pulse energy: 13 mJ

Intensity:  $2.6 \times 10^{10}$  W/cm<sup>2</sup>

Frequency: 1 kHz

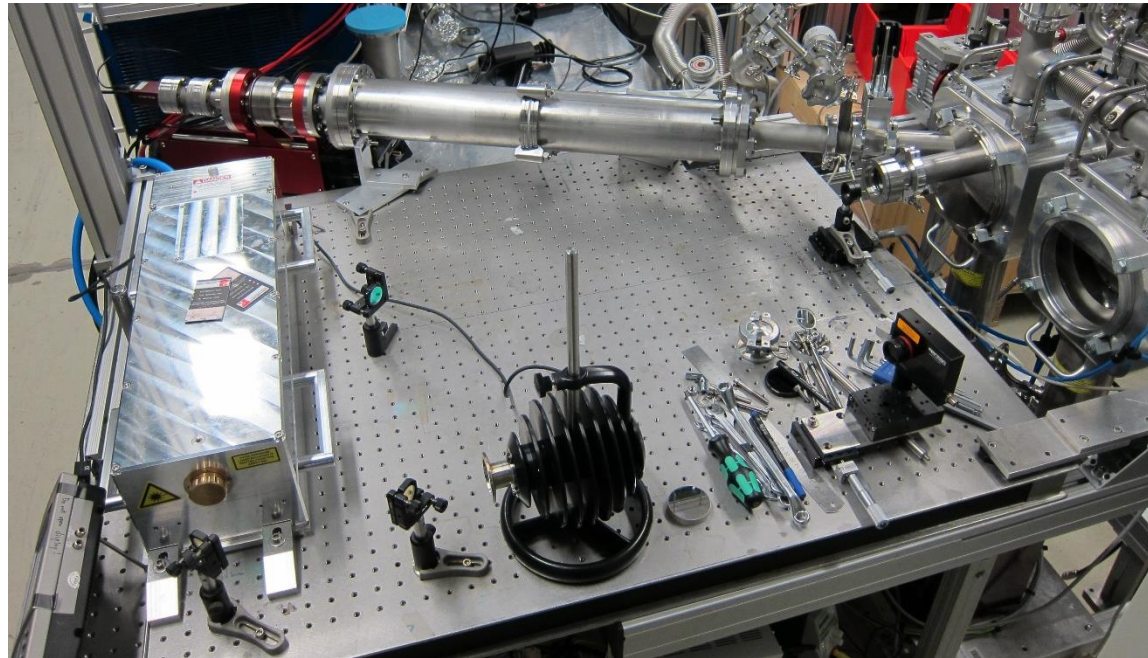
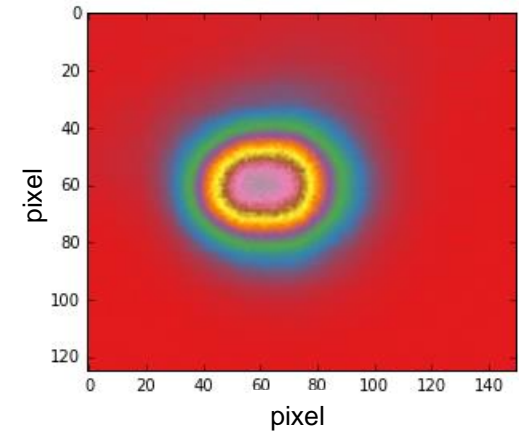
### In-band EUV camera

Optics: Schwarzschild

Magnification: 5.43

CCD pixel size:  $6.5 \times 6.5$   $\mu\text{m}^2$

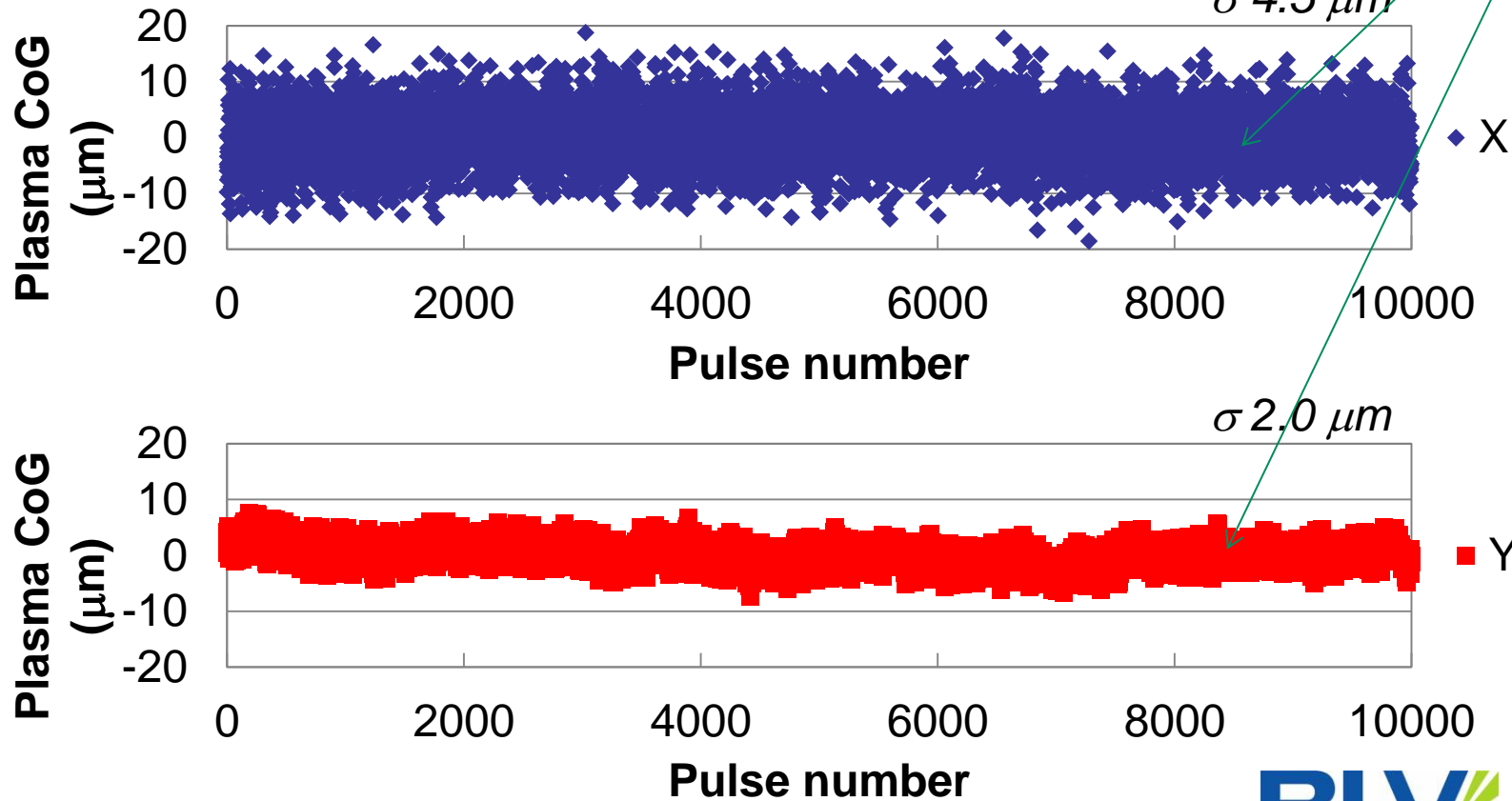
Exposure time: 1 ms (single pulse imaging)





### PoC exp 3

- Stability at 1 kHz based on 10,000 single-pulse images.
- CoG stability was  $4.5\ \mu\text{m}$  (X) and  $2.0\ \mu\text{m}$  (Y).



## *Laser-assisted source*

- ❑ Brightness of Sn-LDP source is sufficiently high for enabling EUV actinic mask inspections (ABI, API and AIMS).
- ❑ Position stability was approximately 6  $\mu\text{m}$ .
- ❑ Local intensity stability was studied.

## *Laser-driven source*

- ❑ Compact LPP source is being studied as EUV and X-ray sources.
- ❑ Sn-LPP PoC experiments showed the brightness of 76  $\text{W}/\text{mm}^2/\text{sr}$  at 15 kHz.
- ❑ Short-time brightness stability was 3-5 % (pulse-to-pulse). Position stability was 2-5  $\mu\text{m}$  (pulse-to-pulse).